



Winbond Electronics Corporation

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Jhubei City, Hsinchu,
Taiwan, R.O.C.

Product Obsolescence Notice

W25Q80B SpiFlash Memories

Notification Date: January 21, 2014

Dear Valued Customer,

This letter is to notify you of Winbond’s intention to terminate production of the W25Q80BV SpiFlash memory. And replace it with the W25Q80DV. Replacement part numbers are listed below:

Winbond Current PN (90nm B-Series)	Winbond Primary Replacement PN (90nm D-Series)
W25Q80BVSSIG	W25Q80DVSSIG
W25Q80BVSNIG	W25Q80DVSNIG
W25Q80BVSVIG	W25Q80DVSVIG
W25Q80BVZPIG	W25Q80DVZPIG
W25Q80BVDAIG	No support

The W25Q80DV device features:

Features

- a) Up to 104MHz Clock at 3.3V
- b) Low power consumption: Active current from 4mA to 1mA
- c) Wide VCC voltage range: 2.5V/3V/3.3V
- d) Fully backward compatible with W25Q80BV
- e) Fast Write (tpp=400uS)

Benefits

- a) Better system performance and timing margin
- b) Provides drop-in replacement capability for seamless transitions

Please refer to the table below for your particular product last time order date and Winbond last shipment date and use this table to determine your last time buys and subsequent request dates. Winbond Electronics reserves the right to limit last time buy quantities based on capacity and material availability. Please notify Winbond as soon as possible if there are any concerns with these this schedule.

90nm Part Number	Notification Date	90nm Last Order Date	90nm Last Ship Date	90nm Part Number	90nm Reliability Report	90nm Mass Production
W25Q80BV	Jan./21/ 2014	Jul./20/ 2014	Jan./19/ 2015	W25Q80DV	Jan./10/ 2014	Jan. 2014

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